

Gr. H. Raisoni College of Engineering Nagpur
2020-2021 ODD Term

AE-1 Examination for Split-II Course Winter-2020
(online mode)

Department :- Electronics Engineering

Semester/Section :- VIIth / A

Date of Examination :- 13/07/2020

Subject :- CMOS VLSI Design

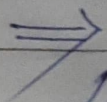
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CO-1

Define NML: Low Noise Margin & NMH: High Noise Margin



NML (Noise Margin Low) :-

NML is defined as the difference in magnitude between the maximum LOW output voltage of the driving gate and the maximum input LOW voltage recognized by the driven gate. Thus,

$$NML \text{ (Noise Margin Low)} = V_{iL} - V_{oL}$$

NMH (Noise Margin High) :-

The value of NMH is difference in magnitude between the minimum HIGH output voltage of the driving

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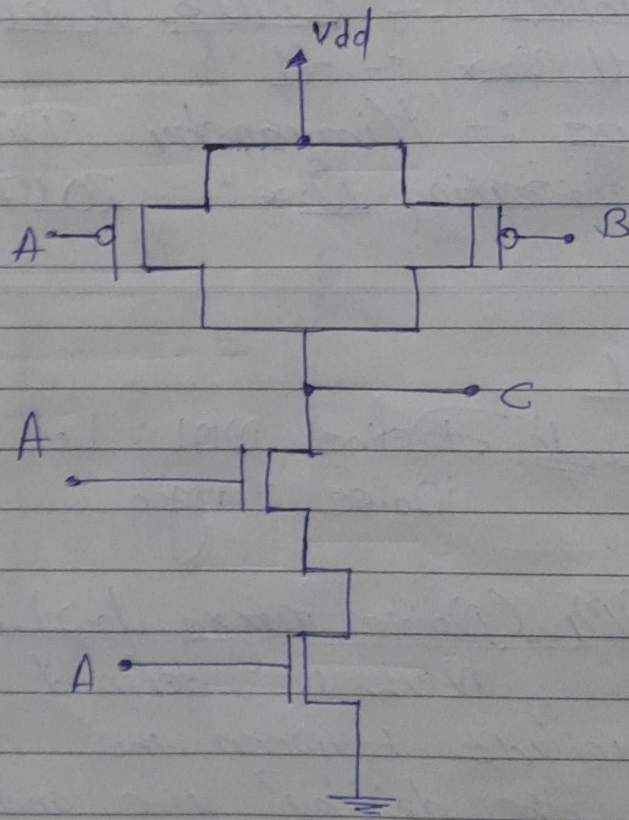
gate and the minimum input HIGH voltage recognized by the receiving gate. Thus,
 NM_H (Noise margin high) $= V_{oh} - V_{ih}$

CO1

Q7 Draw NAND Gate by using Pull up and Pull down Networks with proper truth table.

Pull Up Network

A	B	C
0	0	1
0	1	1
1	0	1
1	1	0



Pull-Down Network

A	B	C
0	0	0
0	1	0
1	0	0
1	1	1

Combined

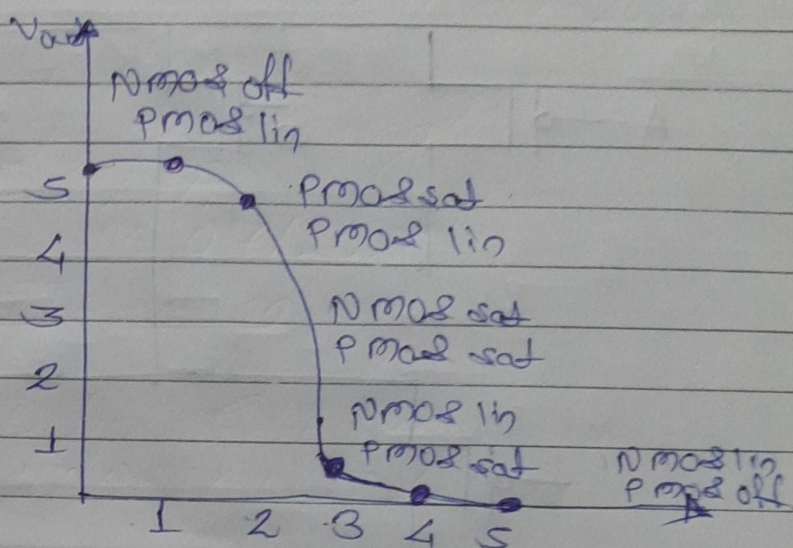
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Network

A	B	C
0	0	1
0	1	1
1	0	1
1	1	0

Co. 1

by Relationship between voltages for the three regions of operation of a CMOS Inverter.



OFF: $V_{\text{Gate to Source}} < V_{\text{Thresh hold}}$

Linear (or OHMIC) : $0 < V_{\text{Drain To Source}} < V_{\text{Gate to Source}}$
 $V_{\text{Threshold}}$

Saturation: $0 < V_{\text{Gate to Source}} - V_{\text{Threshold}} < V_{\text{Drain to Source}}$

CMOS Inverter $\rightarrow V_{\text{Gate To Source}} = V_{\text{in}}$

That is for high input, the nmos transistor drives (pulls-down)

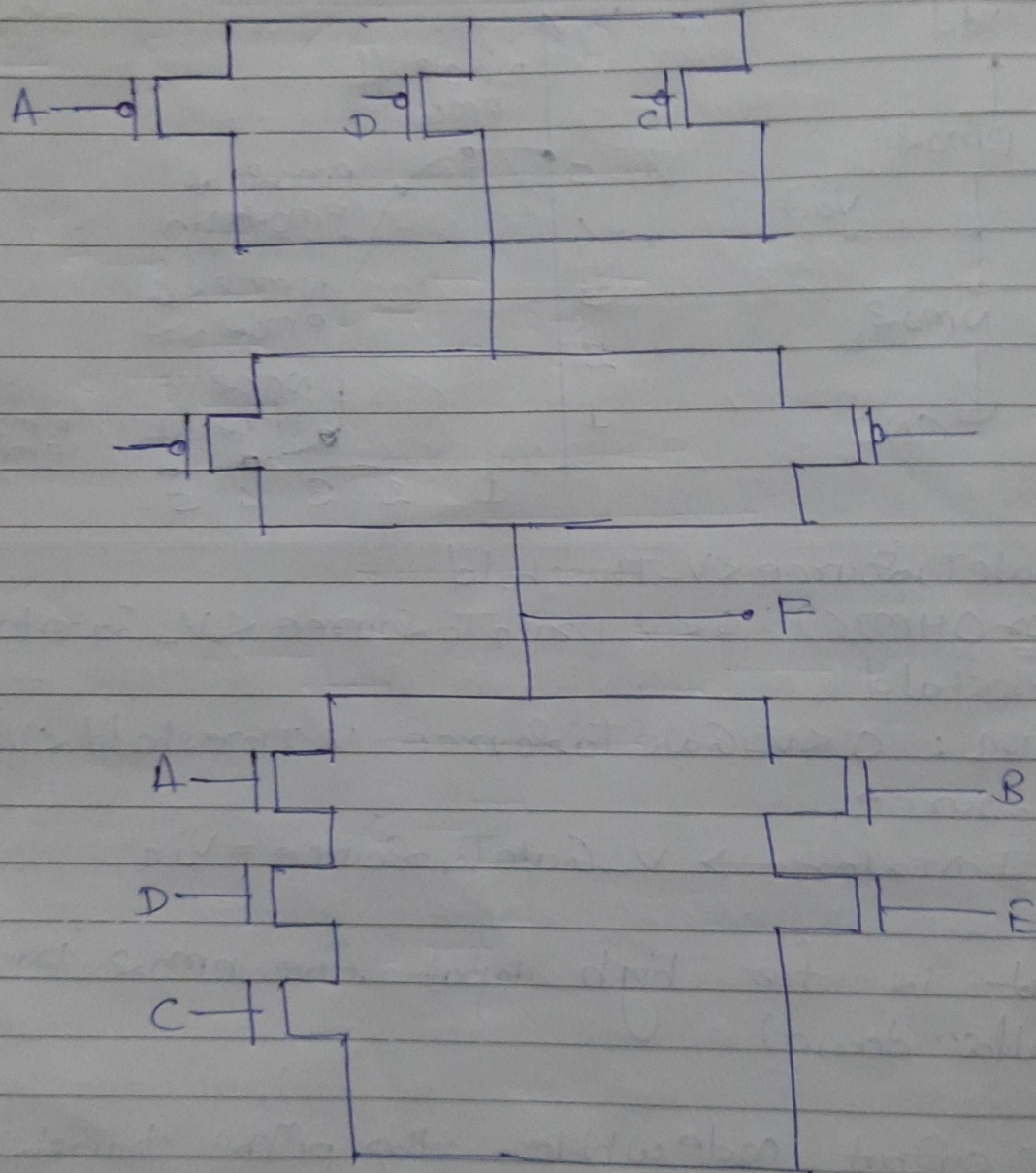
the output node while the pmos transistor acts as the load,

And for low input the pmos transistor drives (pulls up) o/p node with the nmos transistor acts as the load

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Q.2
 \Rightarrow b)

$$F = (A + D + E)(B + E)$$



Effective Ratio

$$\left(\frac{\omega}{L}\right)_{eff} \text{ of } nmos = \frac{1}{1}$$

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 03/07/2020
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$$\frac{1}{1} = \frac{1}{\frac{L}{\omega} + \frac{1}{\omega} + \frac{L}{\omega}}$$

$$\frac{1}{1} = \frac{1}{3L/\omega}$$

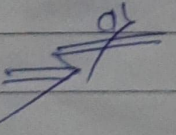
$$\boxed{n_{\text{max}} = \frac{\omega}{L} = \frac{3}{1}}$$

$$P_{\text{max}} = \frac{3}{1} = \left(\frac{\omega}{L}\right)_{\text{eff}}$$

$$= \frac{3}{1} = \frac{1}{4\omega}$$

$$\boxed{P_{\text{max}} = \frac{\omega}{L} = \frac{3}{1}}$$

C.O.2



$$F = (A+B)(C \cdot D)'$$

C02

 \Rightarrow ~~q~~

$$F = ((A+B)C \cdot D)'$$

i.e., $F = ((A+B) \cdot C \cdot D)$

